

Green Products

Technical Data Data Sheet N1918, Rev. -

> KBP4005G THRU KBP410G SINGLE PHASE 4.0AMP GLASS PASSIVATED BRIDGE RECTIFIER

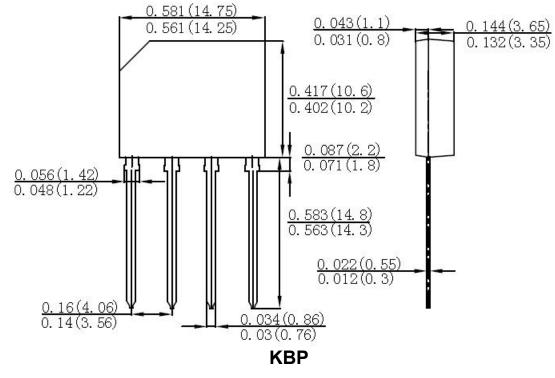
### Features:

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0

### Mechanical Data:

- Case: KBP, molded plastic
- Terminals: plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting position: Any
- Lead Free: For RoHS / Lead Free Version

### Mechanical Dimensions: In mm/Inches



### MARKING, MOLDING RESIN

Marking for Type Number, 1<sup>st</sup> row SSG YYWWL, 2<sup>nd</sup> row Type Number Where YY is the manufacture year WW is the manufacture week code

L is the wafer's Lot Number

- China Germany Korea Singapore United States
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**Maximum Ratings and Electrical Characteristics** Rating at 25°C ambient temperature unless otherwise specified. Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

## Maximum Ratings:

Type number	Symbol	KBP 4005G	KBP 401G	KBP 402G	KBP 404G	KBP 406G	KBP 408G	KBP 410G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{RMS}$	35	70	140	280	420	560	700	v
Average Rectified Output Current (Note 1) @ $T_A=50^{\circ}C$	lo	4.0							
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	120							А

## **Electrical Characteristics:**

Type number	Symbol	KBP 4005G	KBP 401G	KBP 402G	KBP 404G	KBP 406G	KBP 408G	KBP 410G	Unit
Forward Voltage per element @I <sub>F</sub> =4.0A	VF	1.1							V
Peak Reverse Current@TA=25°CAt Rated DC Blocking Voltage@TA=125°C	I <sub>R</sub>	5.0 500							μA

## **Thermal-Mechanical Specifications:**

Type number	Symbol	KBP 4005G	KBP 401G	KBP 402G	KBP 404G	KBP 406G	KBP 408G	KBP 410G	Unit
Typical Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	40							°C/W
Typical Thermal Resistance Junction to Lead	$R_{ extsf{ heta}JL}$	20							
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150							°C
Case Style	КВР								

Note:1. Mounted on glass epoxy PC board with 1.3mm<sup>2</sup> solder pad.

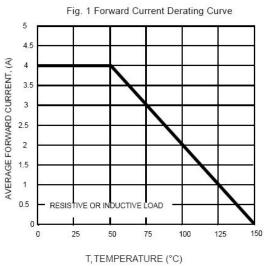
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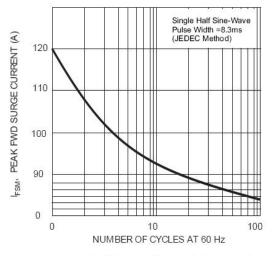
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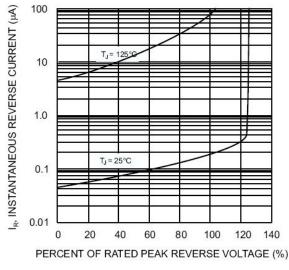
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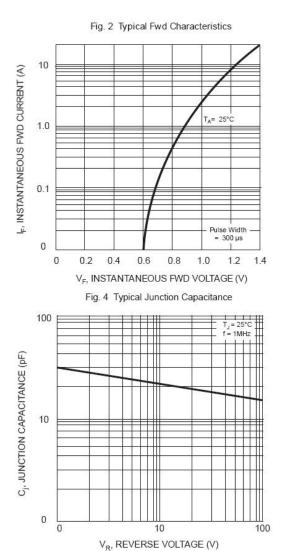












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